

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	369	(antenna adj ratio) same capacitor core same (ring or power) and "716"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:53
S2	2	"20050160389"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 15:57
S3	344	(antenna adj ratio) near3 capacitor core same (ring or power) and "716"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 08:49
S4	0	((antenna adj ratio) near3 capacitor) same core same (ring or power) and "716"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 08:50
S5	1	(antenna adj ratio) same capacitor same core same (ring or power) and "716"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 08:50
S6	1	(antenna adj ratio) same capacitor same core same (ring or power)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 08:51
S7	6	(antenna adj ratio) same capacitor same (ring or power)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 08:55
S8	4	(antenna adj ratio) same capacitor same (ring or power) and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 08:56
S9	32	(antenna adj ratio) same capacitor and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 09:52

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S10	22553	(antenna adj ratio) same capacitor and plasma "326"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 09:52
S11	0	(antenna adj ratio) same capacitor and plasma and "326"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 09:55
S12	1	(antenna adj ratio) and plasma and "326"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 09:56
S13	1	(antenna adj ratio) and capacitor and plasma and "326"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/28 13:36
S14	7560672	JP 11-168196	JPO	OR	ON	2006/01/30 10:00
S15	7560672	JP "11168196"	JPO	OR	ON	2006/01/30 10:00
S16	22	((antenna adj ratio) or charg\$3 or plasma or etch\$3) same MOS same capacit\$3 and "716"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/28 13:18
S17	0	(metal adj interconnect\$3) same substrate same (line near3 (power and ground)) same (plasma near3 charg\$3) same (antenna near3 ratio) same capacit\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/28 13:40
S18	0	(metal adj interconnect\$3) same substrate same (line near3 (power and ground)) and ((plasma near3 charg\$3) same (antenna near3 ratio) same capacit\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/28 13:41
S19	3	((metal adj interconnect\$3) or power or ground) same substrate) and ((plasma near3 charg\$3) same (antenna near3 ratio) same capacit\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/28 16:42
S20	3	((plasma near3 charg\$3) same (antenna near3 ratio)) and (capacit\$3 same (below or beneath) same (metal or interconnect\$3 or conduct\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/28 16:49
S21	1	"6429090".PN.	USPAT; USOCR	OR	ON	2006/02/28 16:57

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S22	343	((insulat\$3 near3 gate) near5 above near5 activ\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 15:59
S23	0	((insulat\$3 near3 gate) near5 above near5 activ\$3) same (antenna adj ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:01
S24	1	((insulat\$3 near3 gate) near5 above near5 activ\$3) and (antenna adj ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:01
S25	1	((insulat\$3 near3 gate) near5 above near5 activ\$3) and (antenna near3 ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:01
S26	136	((insulat\$3 near3 gate) near5 above near5 activ\$3) and ((antenna near3 ratio) or plasma)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:02
S27	5	((insulat\$3 near3 gate) near5 above near5 activ\$3) and ((antenna near3 ratio) or (plasma near3 charg\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:08
S28	1	((insulat\$3 adj gate adj electrode) near5 above near5 activ\$3) and ((antenna near3 ratio) or (plasma near3 charg\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:09
S29	1	((insulat\$3 adj gate adj electrode) near5 above near5 activ\$3) and (antenna or (plasma near3 charg\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:09
S30	34	((gate adj electrode) near5 above near5 activ\$3) and (antenna or (plasma near3 charg\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:19
S31	1	((gate adj electrode) near5 above near5 activ\$3) same capacit\$3 and antenna and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:21

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S32	1	((gate adj electrode) near5 above near5 activ\$3) same capacit\$3 and (antenna same ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:21
S33	1	((gate adj electrode) near5 above near5 activ\$3) same capacit\$3 and antenna	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:21
S34	0	(antenna near3 ration) same (gate adj electrode) same (ground and power) same (active near3 (region or area))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:27
S35	0	(antenna near3 ration) same (gate adj electrode) same (active near3 (region or area))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:27
S36	0	(antenna near3 ration) same (gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:27
S37	1	(antenna near3 ratio) same (gate adj electrode) same (ground and power) same (active near3 (region or area))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:27
S38	8	(antenna near3 ratio) same (gate adj electrode) same (active near3 (region or area))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:00
S39	1	(antenna near3 ratio) same (gate adj electrode) same (active near3 (region or area)) and ((MOS near3 capacit\$4) same (ring near3 (core or power) same (below or beneath or under)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:03
S40	1	(antenna near3 ratio) same (gate adj electrode) same (active near3 (region or area)) and ((MOS near3 capacit\$4) same (ring near3 (core or power) same (below or beneath or under)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:02

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S41	1	(antenna near3 ratio) same (gate adj electrode) same (active near3 (region or area)) and ((MOS near3 (capacit\$4 or transistor)) same (ring near3 (core or power) same (below or beneath or under)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:04
S42	1	(antenna near3 ratio) same (gate adj electrode) same (active near3 (region or area)) and (MOS same (ring near3 (core or power)) same (below or beneath or under))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:05
S43	1	(antenna near3 ratio) same (gate adj electrode) and (MOS same (ring near3 (core or power)) same (below or beneath or under))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:06
S44	1	(antenna near3 ratio) same (MOS same (ring near3 (core or power)) same (below or beneath or under))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:06
S45	12	(MOS same (ring near3 (core or power)) same (below or beneath or under))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:09
S46	1	(MOS same (ring near3 (core or power)) same (below or beneath or under)) and (plasma same (damag\$3 or charg\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:10
S47	1	(MOS same (ring near3 (core or power)) same (below or beneath or under)) and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:10
S48	7	((MOS or transistor or capacit\$3) same (ring near3 (core or power)) same (below or beneath or under)) and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:13
S50	1	((MOS or transistor or capacit\$3) same (ring near3 (core or power)) same (below or beneath or under)) and (plasma and (antenna near3 ratio))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:14

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S51	4	((gate adj electrode) near5 above near5 activ\$3) and ((antenna near5 ratio) or (plasma near3 charg\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 14:17
S52	1	((gate adj electrode) same above near5 activ\$3) and ((antenna near5 ratio) or (plasma near3 charg\$3)) and (ring near3 (power or core)) and (MOS near3 capacit\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:28
S53	30	(MOS near3 capacit\$4) and plasma and (antenna near3 ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:29
S54	1	(MOS near3 capacit\$4) and plasma and (antenna near3 ratio) and (ring near3 (power or core))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:29
S55	16	(MOS near3 capacit\$4) and plasma and (antenna near3 ratio) and power	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:29
S56	2	"20040241399".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 12:49
S57	21	protect\$3 same plasma same mos same capacit\$3 same (plac\$3 or placement or position\$3 or are or region)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 12:58
S58	1	protect\$3 same plasma same mos same capacit\$3 same (plac\$3 or placement or position\$3 or are or region) and antenna	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:24
S64	495	mos same capacitor same active same (gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:34
S65	1	mos same capacitor same (active adj area) same (insulated adj gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:30

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S66	28	mos same capacitor same (active adj area) same (gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:32
S67	6	mos same capacitor same (active adj area) same (insulat\$3 near3 gate near3 electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:31
S68	1	mos same capacitor same (active adj area) same (insulat\$3 near3 gate near3 electrode) and (antenna near3 ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:31
S69	1	mos same capacitor same (active adj area) same (gate near3 electrode) and (antenna near3 ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:31
S70	13	mos same capacitor same (active adj area) same (gate adj electrode) and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:34
S71	2	mos same capacitor same active same (gate adj electrode) and (antenna near3 ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 13:34
S72	7	((MOS or transistor or capacit\$3) same (ring near3 (core or power)) same (below or beneath or under)) and (plasma or (antenna near3 ratio))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 14:00
S73	4	(mos near3 capacit\$3) same (ring near3 (power or core))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 14:42
S74	182	(mos near3 capacit\$3) same power same (below or beneath or under)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 14:42
S75	684	(mos near3 capacit\$3) same (power or volt\$4) same (below or beneath or under)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 16:04

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S76	4	(mos near3 capacit\$3) same (power or volt\$4) same (below or beneath or under) and (plasma same antenna same ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 15:17
S77	5	(mos near3 capacit\$3) same (plac\$3 or distribut\$3 or position\$3 or area or region) same (gate near3 electrode) and (plasma with antenna with ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 15:36
S78	1	(mos near3 capacit\$3) same (plac\$3 or distribut\$3 or position\$3 or area or region) same ((interconnect near3 line) or power) same (gate near3 electrode) and (plasma with antenna with ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 15:37
S79	4	(mos near3 capacit\$3) same (power or volt\$4 or (interconnect\$3 near3 line)) same (below or beneath or under) and (plasma same antenna same ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 15:54
S80	21	(mos near3 capacit\$3) same (power or volt\$4 or (interconnect\$3 near3 line)) and (plasma same antenna same ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 15:54
S81	0	(mos near3 capacit\$3) same (power or volt\$4) same (below or beneath or under) and "716"/\$.ccls. and "438"/\$.ccls. and "257"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 16:05
S82	332	(mos near3 capacit\$3) same (power or volt\$4) same (below or beneath or under) and ("716"/\$.ccls. or "438"/\$.ccls. or "257"/\$.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 16:05
S83	4	(mos near3 capacit\$3) same (power or volt\$4) same (below or beneath or under) and ("716"/\$.ccls. or "438"/\$.ccls. or "257"/\$.ccls.) and (plasma same antenna same ratio)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 16:06
S84	2	(mos near3 capacit\$3) same (power or volt\$4) same (below or beneath or under) and ("716"/\$.ccls. or "438"/\$.ccls. or "257"/\$.ccls.) and (plasma same antenna same ratio) and (gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 16:06

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S85	1605	ring same capacitor same (below or beneath or under)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:36
S86	67891	capacitor same (active or source or drain or channel) same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:37
S87	747568	(active or source or drain or channel) same (connect\$4 or interconnect\$4 or rout\$4 or coupl\$3) same (power or ground or earth or vdd or vss or vcc or potential or gnd or voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:39
S88	229937	gate same (connect\$4 or interconnect\$4 or rout\$4 or coupl\$3) same (power or ground or earth or vdd or vss or vcc or potential or gnd or voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:39
S89	225	S85 and S86 and S87 and S88	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:40
S90	33	S89 and ("257"/\$.ccls. or "438"/\$.ccls. or "716"/\$.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:41
S91	400646	\$2mos or (metal adj oxide adj semiconductor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:41
S92	641	7and S90	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:42
S93	1605	ring same capacitor same (below or beneath or under)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:53
S94	67891	capacitor same (active or source or drain or channel) same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:54

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S95	716724	(active or source or drain or channel) same (connect\$4 or interconnect\$3 or rout\$3 or coupl\$4) same (power vdd or vcc or voltage or potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:56
S96	220459	gate same (connect\$4 or interconnect\$3 or rout\$3 or coupl\$4) same (power vdd or vcc or voltage or potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:56
S97	218	S93 and S94 and S95 and S96	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:56
S98	29	S93 and S94 and S95 and S96 and ("257"/\$.ccls. or "438"/\$.ccls. or "716"/\$.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 17:57
S99	26	S98 and (\$2mos or (metal adj oxide adj semiconductor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:16
S100	2	S98 and (\$2mos or (metal adj oxide adj semiconductor)) and plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 18:06
S101	1605	ring same capacitor same (below or beneath or under)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:17
S102	67902	capacitor same (active or source or drain or channel) same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:17
S103	716915	(active or source or drain or channel) same (connect\$4 or interconnect\$3 or rout\$3 or coupl\$4) same (power vdd or vcc or voltage or potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:17
S104	220503	gate same (connect\$4 or interconnect\$3 or rout\$3 or coupl\$4) same (power vdd or vcc or voltage or potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:17

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S10 5	29	S101 and S102 and S103 and S104 and ("257"/\$.ccls. or "438"/\$.ccls. or "716"/\$.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:17
S10 6	0	S105 and (\$2mos or (metal adj oxide adj semiconductor)) and capacotir and diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:17
S10 7	3141	plasma and capacitor and diode and \$2MOS	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:18
S10 8	387	plasma and (capacitor same diode same \$2MOS)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:18
S10 9	26	plasma same capacitor same diode same \$2MOS	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:29
S11 0	7	plasma same capacitor same diode same \$2MOS same antenna	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/06 07:19
S11 1	3	(plasma near5 damag\$3 or charch\$3) same capacitor same diode same \$2MOS	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/07 12:16
S11 2	1	(antenna adj ratio) same (line near5 power near5 ground) and plasma and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/07 12:17
S11 3	1	(antenna adj ratio) same (line near5 power near5 ground) and (plasma same capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/07 12:20
S11 4	0	(antenna adj ratio) same (line near5 power near5 ground) same capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/07 12:20

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S11 5	1	(antenna adj ratio) same (line near5 power near5 ground)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/07 12:20
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